

BGE788

750 MHz, 34 dB gain push-pull amplifier Rev. 04 — 30 March 2005

Product data sheet



1.1 General description

Hybrid high dynamic range amplifier module in a SOT115J package operating at a supply voltage of 24 V (DC). The module consists of two cascaded stages both in cascode configuration.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Excellent linearity
- Extremely low noise
- High gain
- Excellent return loss properties

1.3 Applications

Single module line extender in CATV systems operating in the 40 MHz to 750 MHz frequency range.

1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz	33.5	-	34.5	dB
		f = 750 MHz	34	-	-	dB
I _{tot}	total current consumption (DC)	$V_B = 24 V$	<u>11</u> 290	-	320	mA

^[1] The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.



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2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol			
1	input					
2	common	1 3 5 7 9	5			
3	common		$\frac{1}{2}$			
5	+V _B		2 3 7 8			
7	common		sym095			
8	common					
9	output					

3. Ordering information

Table 3: Ordering information

Type number	Package				
	Name	Description	Version		
BGE788	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2×6 -32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J		

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_B	supply voltage		-	25	V
Vi	RF input voltage		-	55	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperat	ure	-20	+100	°C

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5. Characteristics

Table 5: Characteristics

Bandwidth 40 MHz to 740 MHz; $V_B = 24~V$; $T_{case} = 30~^{\circ}C$; $Z_S = Z_L = 75~\Omega$; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
G _p	power gain	f = 50 MHz		33.5	-	34.5	dB
		f = 750 MHz		34	-	-	dB
SL	slope cable equivalent	f = 40 MHz to 750 MHz		0.5	-	2.5	dB
FL	flatness of frequency response	f = 40 MHz to 750 MHz		-	-	±0.5	dB
S ₁₁	input return	f = 40 MHz to 80 MHz		20	-	-	dB
	losses	f = 80 MHz to 160 MHz		18.5	-	-	dB
		f = 160 MHz to 320 MHz		17	-	-	dB
		f = 320 MHz to 640 MHz		15.5	-	-	dB
		f = 640 MHz to 750 MHz		14	-	-	dB
S ₂₂	output return losses	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		18.5	-	-	dB
		f = 160 MHz to 320 MHz		17	-	-	dB
		f = 320 MHz to 640 MHz		15.5	-	-	dB
		f = 640 MHz to 750 MHz		14	-	-	dB
φ _{s21}	phase response	f = 50 MHz		135	-	225	deg
СТВ	composite triple beat	110 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 745.25 MHz		-	-	-49	dB
X _{mod}	cross modulation	110 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 55.25 MHz		-	-	–51	dB
CSO	composite second order distortion	110 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 746.5 MHz		-	-	-52	dB
d ₂	second order distortion		[1]	-	-	-64	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$	[2]	58	-	-	dBmV
F	noise figure	f = 750 MHz		-	-	7	dB
PM	positive match	f = 40 MHz to 2 GHz		-	-	3	dB
l _{tot}	total current consumption (DC)		[3]	290	-	320	mA

^[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.

^[2] Measured according to DIN45004B; f_p = 740.25 MHz; V_p = V_o ; f_q = 747.25 MHz; V_q = V_o - 6 dB; f_r = 749.25 MHz; V_r = V_o - 6 dB; measured at f_p + f_q - f_r = 738.25 MHz.

^[3] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.



6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

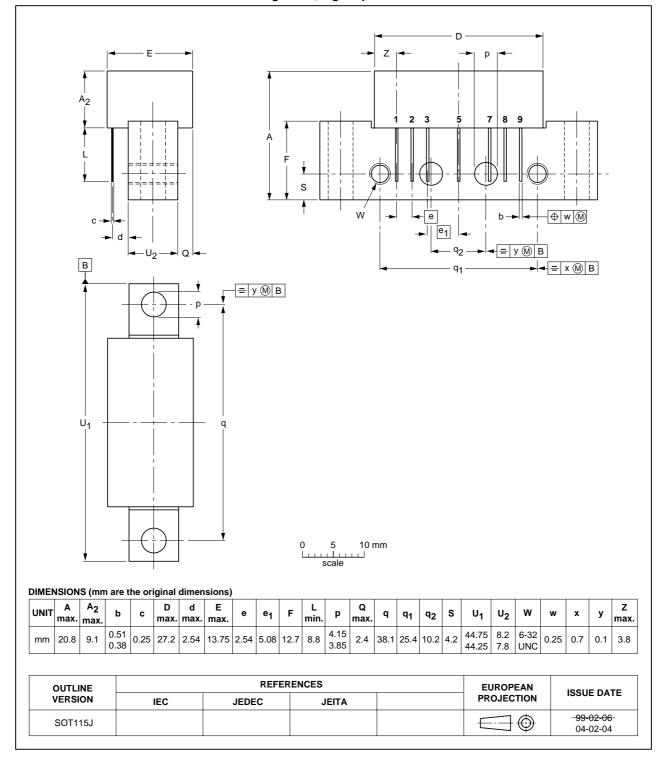


Fig 1. Package outline SOT115J

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Revision history

Table 6: **Revision history**

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGE788_4	20050330	Product data sheet	-	9397 750 14433	BGE788_3
Modifications:		t of this data sheet has been standard of Philips Semic		omply with the new	representation and
BGE788_3	20011115	Product specification	-	9397 750 08812	BGE788_2
BGE788_2	19980108	Product specification	-	9397 750 02981	BGE788_N_1
BGE788_N_1	19970505	Preliminary specification	-	9397 750 02294	-

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8. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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